MA999

Silicon epitaxial planer type

For switching circuits

■ Features

- MA704A and MA151K chip with two elements incorporated
- Short reverse recovery period t_{rr}
- Automatic mounting possible

■ Absolute Maximum Ratings (Ta= 25°C)

• Unit-1(MA704A)

Parameter	Symbol	Rating	Unit	
Reverse voltage (DC)	V _R	30	V	
Peak reverse voltage	V _{RM}	30	V	
Forward current (DC)	I_{F}	30	mA	
Peak forward current	I_{FM}	150	mA	
Junction temperature	T _j	125	°C	
Storage temperature	T _{stg}	-55 to + 125	°C //	

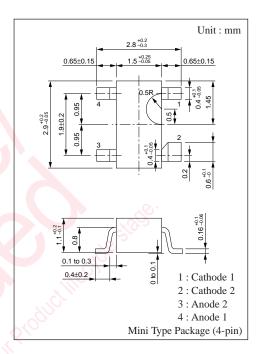
Unit-2(MA151K)

Parameter	Symbol	Rating	Unit	
Reverse voltage (DC)	V_R	40	V	
Peak reverse voltage	V _{RM}	40	(V)	
Forward current (DC)	I _F	100	mA	
Peak forward current	I_{FM}	225	mA	
Non-repetitive peak forward surge current	I _{FSM} *	500	mA	
Junction temperature	T_j	125	°C	
Storage temperature	T _{stg}	- 55 to +125	°C	

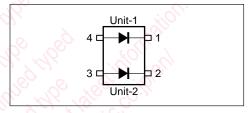
^{*}t=1s

■ Marking





■ Internal Connection



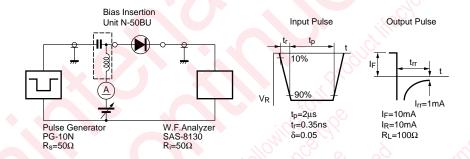
■ Electrical Characteristics (Ta= 25°C)

● Unit-1

Parameter	Symbol	Condition	min	typ	max	Unit
Reverse current (DC)	I _R	$V_R = 30V$			300	nA
Forward voltage (DC)	V_{F1}	I _F = 1mA			0.4	V
	V _{F2}	I _F = 30mA			1.0	V
Terminal capacitance	Ct	V _R =1V, f=1MHz		1.5		pF
Reverse recovery time t	4 *	$I_F = I_R = 10 \text{mA}$		1.0		
	t _{rr} *	$I_{rr}=1$ mA, $R_L=100\Omega$	1.0		ns	
Detection efficiency η		$V_{in}=3V_{(peak)}, f=30MHz$		65		
	η	V_{in} = $3V_{(peak)}$, f= $30MHz$ R_L = $3.9k\Omega$, C_L = $10pF$				%

Note 1: Rated input/output frequency: 2000MHz

- 2 : This Schotky barrier diode is sensitive to electric shock (static electricity, etc.). Due attention to the electric charge of a human body or the leakage from the equipment in use.
- $3:*t_{rr}$ measuring circuit

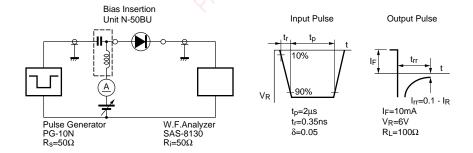


• Unit-2

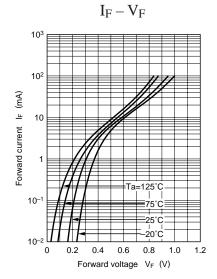
Parameter	Symbol	Condition	min	typ	max	Unit
Reverse current (DC)	I_R	$V_R = 35V$	1000		100	nA
Forward voltage (DC)	V_{F}	I _F =100mA	10.	0.95	1.2	V
Reverse voltage (DC)	V_R	I _R =100μA	40			V
Terminal capacitance	$C_{\rm t}$	V _R = 0V, f=1MHz		0.9	2	pF
Reverse recovery time t_{rr} *	I _F =10mA, V _R = 6V			2		
	$I_{rr}=0.1 \cdot I_{R}, R_{L}=100\Omega$			3	ns	

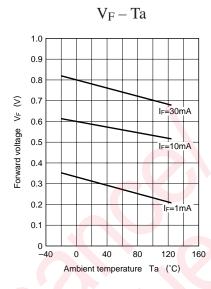
Note 1: Rated input/output frequency: 100MHz

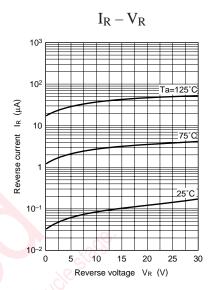
2: * t_{rr} measuring circuit

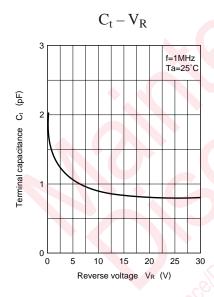


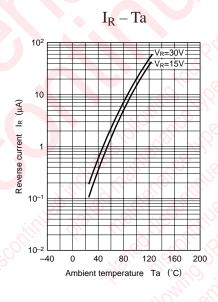
Characteristics chart of Unit-1(MA704A) (Between pins 1 and 4)



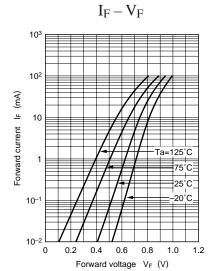


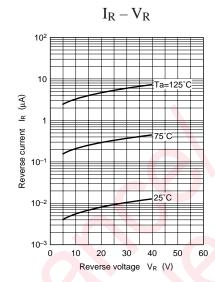


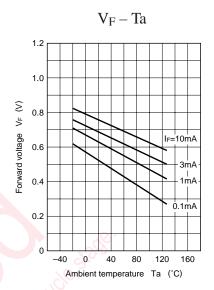


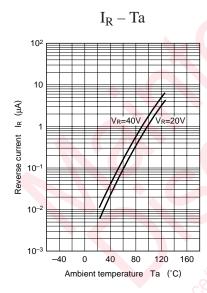


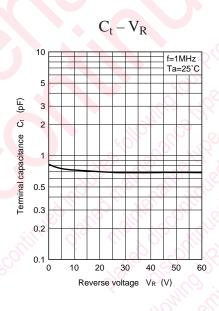
Characteristics chart of Unit-2(MA151K) (Between pins 2 and 3)











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